



# EGP10A THRU EGP10M

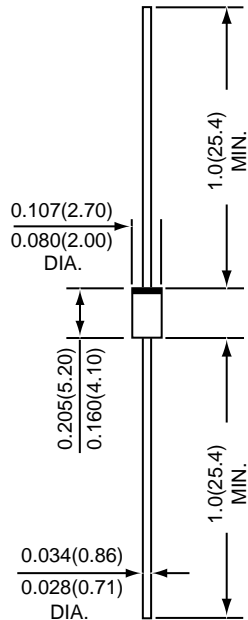
## SINTERED GLASS PASSIVATED JUNCTION HIGH EFFICIENT RECTIFIER

Reverse Voltage - 50 to 1000 Volts

Forward Current - 1.0 Ampere

**PATENTED**

DO-204AL



\*Dimensions in inches and (millimeters)

**SUPEREX II**™



### FEATURES

- \* GPRC (Glass Passivated Rectifier Chip) inside
- \* Glass passivated cavity-free junction
- \* Superfast recovery time for high efficiency
- \* Low forward voltage , high current capability
- \* Low leakage current
- \* High surge current capability
- \* High temperature soldering guaranteed: 260°C/10 seconds, 0.375" (9.5mm) lead length, 5lbs. (2.3 kg) tension
- \* Plastic package has Underwriters Laboratory Flammability Classification 94V-0

### MECHANICAL DATA

**Case :** JEDEC DO-204AL molded plastic over glass body  
**Terminals :** Plated axial leads , solderable per MIL-STD-750, Method 2026  
**Polarity :** Color band denotes cathode end  
**Mounting Position :** Any  
**Weight :** 0.012 ounces , 0.3 gram

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.	SYMBOLS	EGP10								UNITS
		A	B	D	F	G	J	K	M	
Maximum repetitive peak reverse voltage	VRRM	50	100	200	300	400	600	800	1000	Volts
Maximum RMS voltage	VRMS	35	70	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	VDC	50	100	200	300	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length (SEE FIG.1)	I (AV)	1.0								Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	30				25				Amps
Maximum instantaneous forward voltage at 1.0 A	VF	1.0			1.25		1.7			Volts
Maximum DC reverse current at rated DC blocking voltage	IR	5				50				uA
Maximum reverse recovery time (NOTE 1)	trr	50				75				nS
Typical junction capacitance (NOTE 2)	CJ	15								pF
Typical thermal resistance (NOTE 3)	RθJA	50								°C / W
Operating junction and storage temperature range	TJ,TSTG	-65 to +175				-55 to +150				°C

NOTES : (1) Reverse recovery test condition : IF 0.5A, IR=1.0A, Irr=0.25A  
 (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts  
 (3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead lengths, P.C.B. mounted.

# RATINGS AND CHARACTERISTIC CURVES EGP10A THRU EGP10M

FIG.1 - FORWARD CURRENT DERATING CURVE

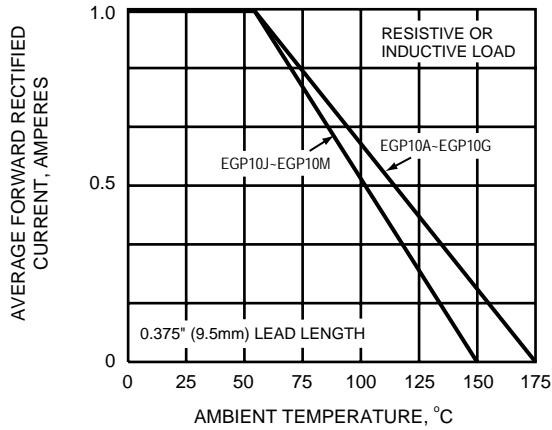


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

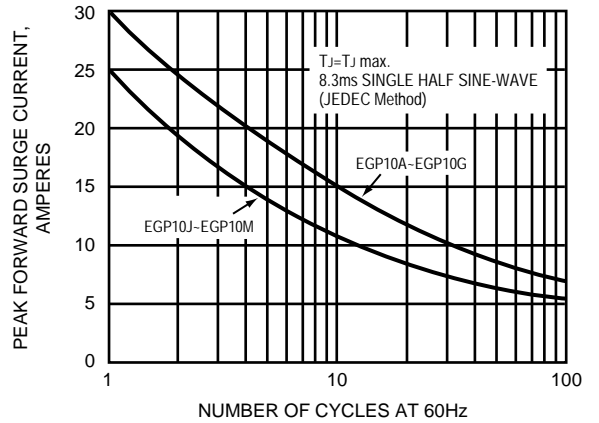


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

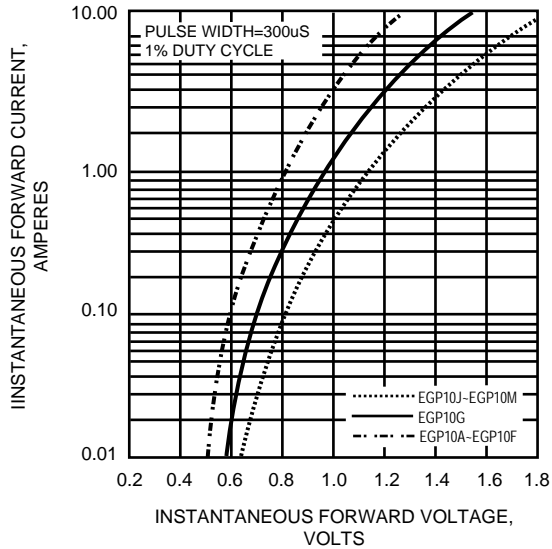


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

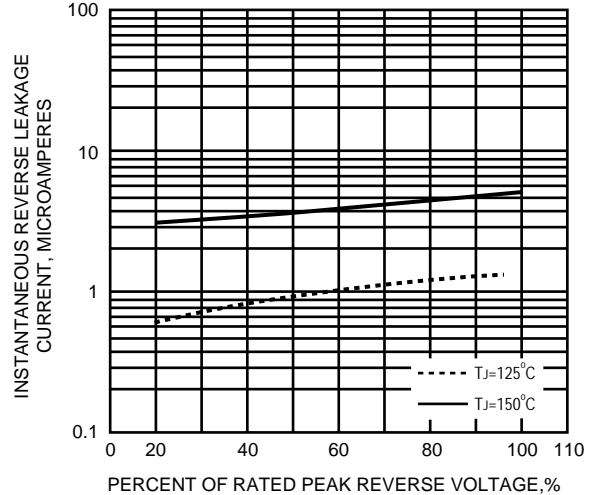


FIG.5 - TYPICAL JUNCTION CAPACITANCE

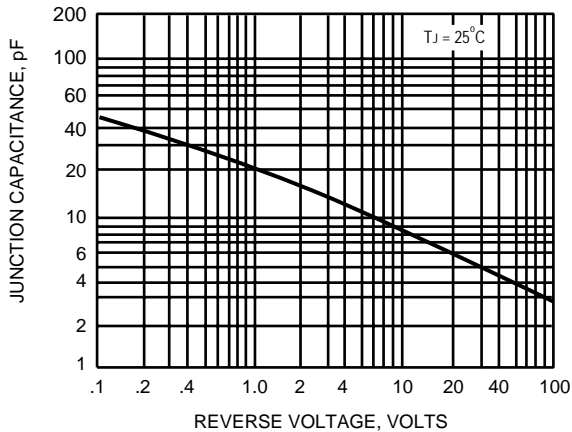


FIG.6 - TYPICAL TRANSIENT THERMAL IMPEDANCE

